

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

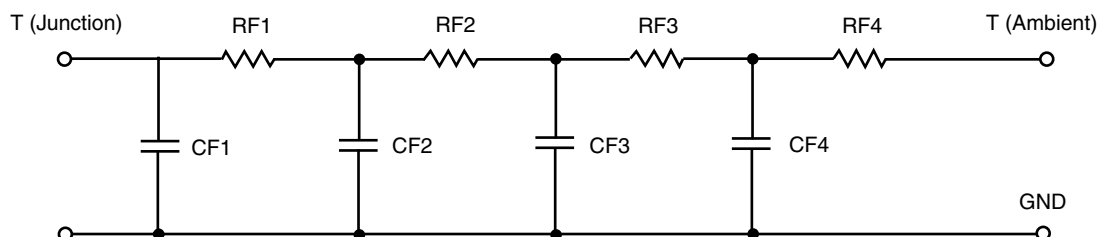


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	13.8615	N/A	11.4493
RT2	46.1252	N/A	27.4200
RT3	39.6459	N/A	26.0457
RT4	50.3664	N/A	24.9593
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	176.1896 u	N/A	72.5167 u
CT2	1.2915 m	N/A	3.6944 m
CT3	12.8507 m	N/A	700.8137 u
CT4	1.4505	N/A	1.3702 m

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	13.0019	N/A	15.1544
RF2	53.4507	N/A	32.2783
RF3	33.9623	N/A	29.2519
RF4	49.5851	N/A	13.3027
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	102.2003 u	N/A	63.9325 u
CF2	878.4586 u	N/A	315.2523 u
CF3	13.6139 m	N/A	373.9146 u
CF4	1.4463	N/A	7.1475 m

Note

N/A indicates not applicable

